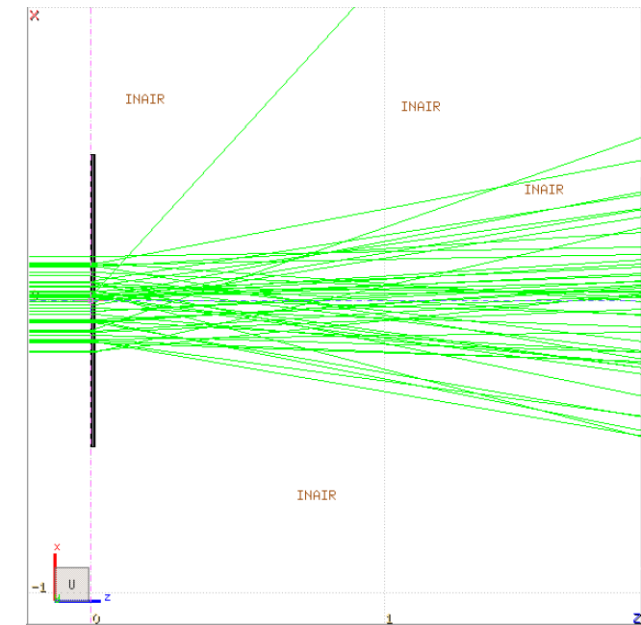


Exercise : Thresholds

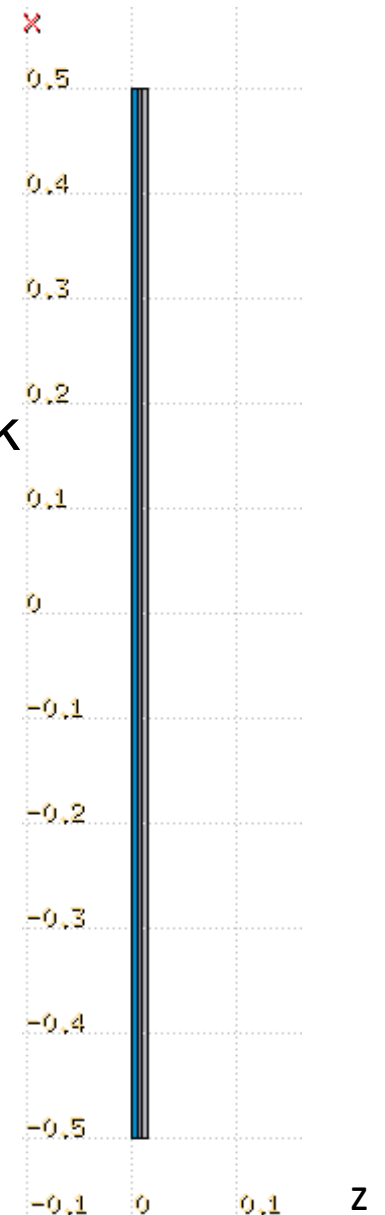
Aim of the exercise:

- Examine the effect of setting different threshold values
- Further interaction with the FLUKA manual
- Practice the use of preprocessor directives
- Strengthen plotting skills



Input file

- 10 MeV electron beam
 - Circular beam with 2 mm radius
 - Starting at $x=0$ cm, $y=0$ cm, $z=-1$ cm
- Cylindrical target along z , 5-mm radius, split in three layers, each 50 μm thick
 - Set to $\text{H}_2\text{O} - \text{Pb} - \text{Al}$
- Thin layers require high tracking precision. Thus, we set
 - **DEFAULT PRECISION**
- Notice that three preprocessor variables are defined
 - HI-THR, LOW-THR, VLOW-THR
- **USRBIN** scoring DOSE over the entire target
 - 1 μm bins in z , 1 bin in R , unformatted unit 55



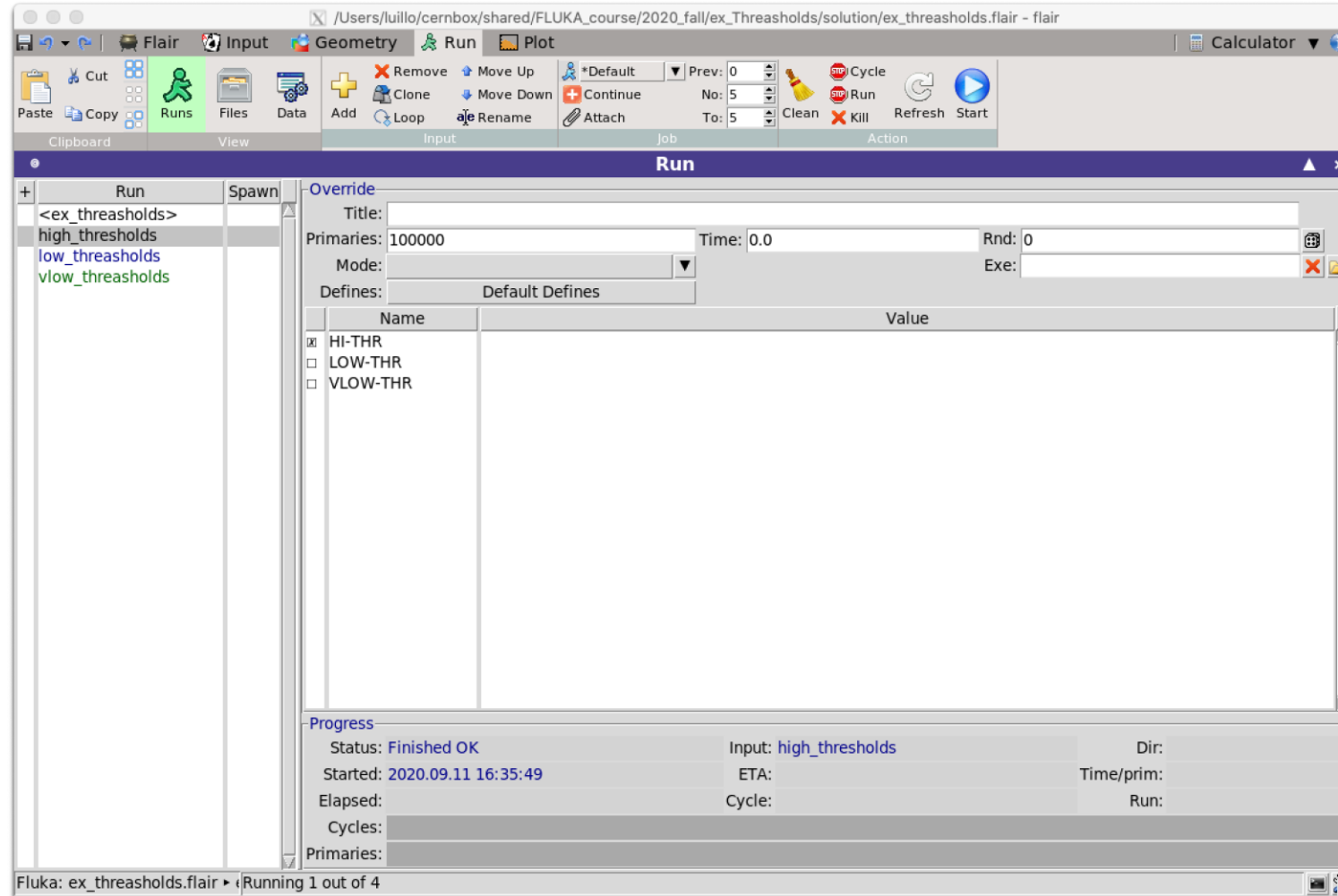
Add EMFCUT cards

- Set both production and transport thresholds in all materials
 - Hint: when specifying the range of materials/regions, use @LASTMAT/@LASTREG as needed to refer to the last material or region, respectively
- Use preprocessor instructions to prepare three runs, one for each threshold case, exploiting the already defined preprocessor variables:

```
#if HI-THR
    photons: 1 keV ,      electrons: 1 MeV kinetic energy,      FUDGEM=1
#elif LOW-THR
    photons: 1 keV ,      electrons: 100 keV kinetic energy,      FUDGEM=1
#elif VLOW-THR
    photons: 1 keV ,      electrons: 10 keV kinetic energy,      FUDGEM=0.5
#endif
```

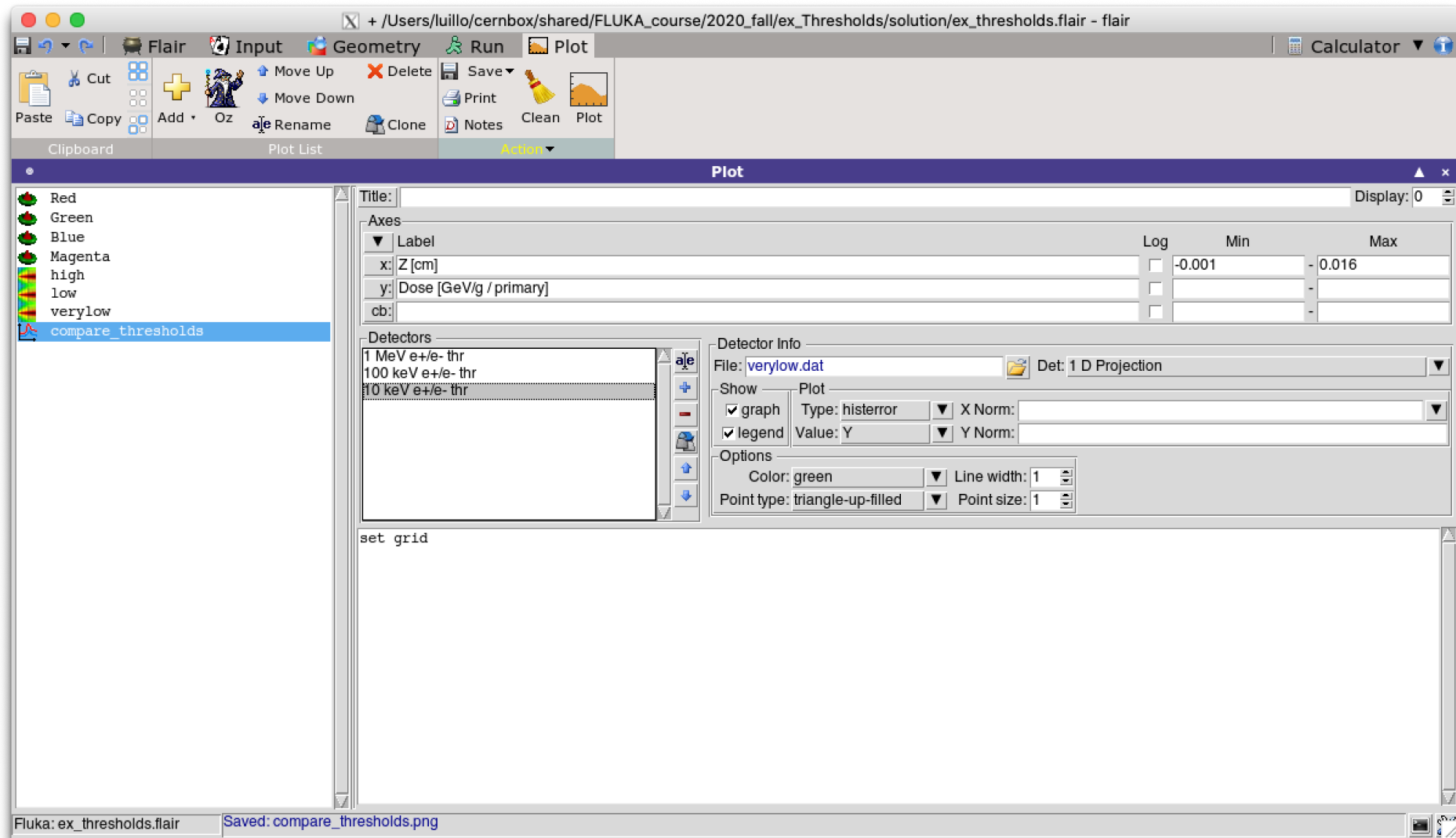
- Note that the electron threshold is 100 keV in case of **PRECISION**, corresponding to our LOW-THR case
- Reminder: stopping powers and ranges for electrons, protons, and He ions are available on the NIST webpage: <https://physics.nist.gov/PhysRefData/Star/Text/intro.html>

Run



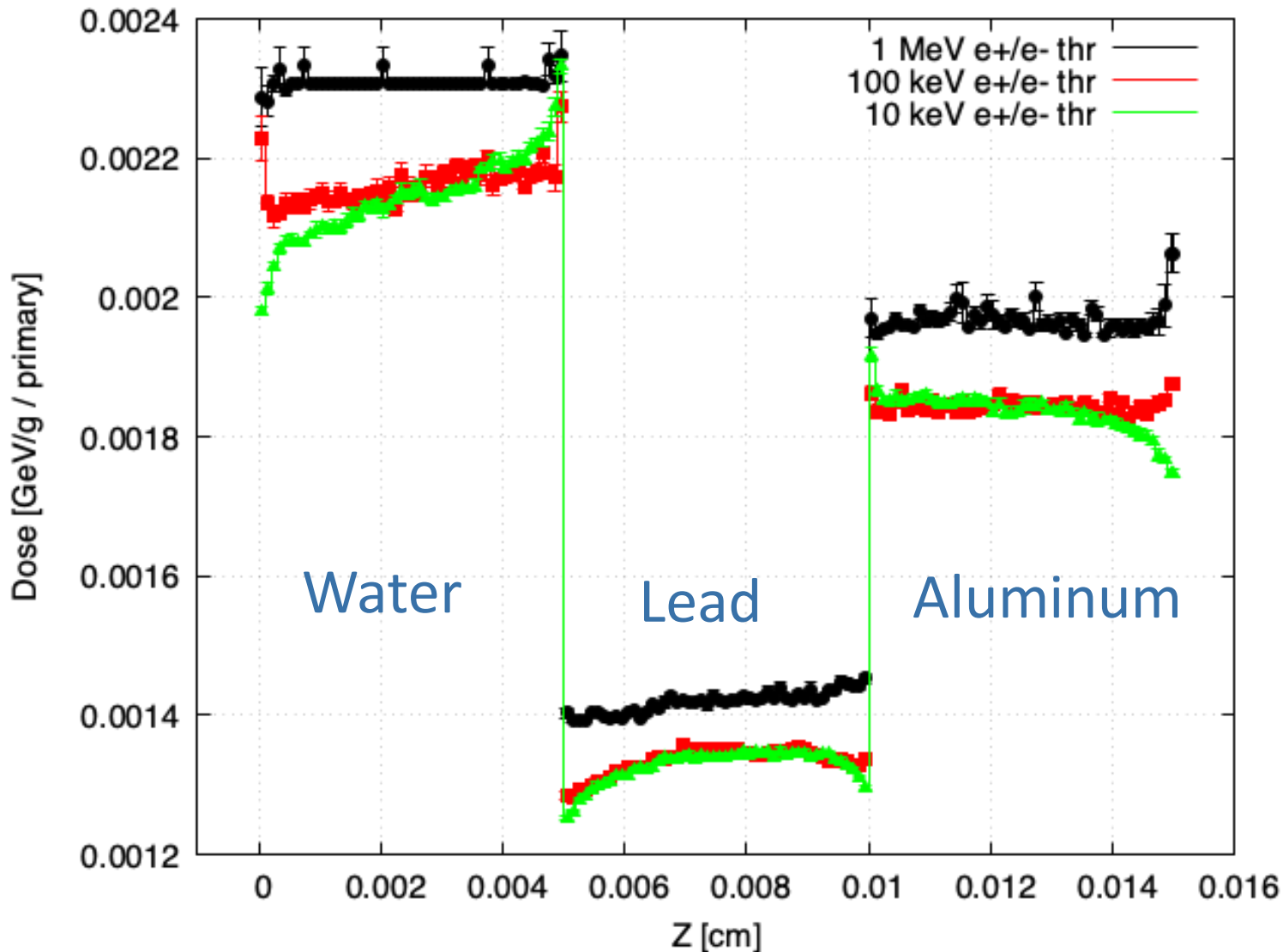
Run three simulations corresponding to high, low, or very low threshold values, with 5 cycles \times 100000 primaries for each case
The three runs are already set up in the Flair project
Should take less than \sim 5 minutes on a reasonable machine.

Plot and compare the results



The plots are already set up in the Flair project

Compare depth-dose curve for various thresholds



- Premature dose deposition for 1-MeV threshold
- Correct deposition on average for 100-keV threshold (the value with DEFAULTS->PRECISION), but lacking details
- More refined result for 10-keV threshold
- Net flow of low energy electrons across boundary from high Z to low Z materials
- Physical effect!

Note

- Correct threshold values depend on the granularity of your geometry/scorings
- Do not blindly rely on default values
- Carefully set threshold values accordingly (range tables are helpful!)
- Do not forget to set the FUDGEM parameter



One final detail

EMFFIX Mat1: WATER Max Frac.1: .01 Print:
Mat2: LEAD Max Frac.2: .01
Mat3: ALUMINUM Max Frac.3: .01

